

DESCRIPTION

This UPS5100e3 in the Powermite3[®] package is a high efficiency Schottky rectifier that is also RoHS compliant offering high current/power capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies. In addition to its size advantages, the Powermite3[®] package includes a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly and a unique locking tab act as an efficient heat path to the heat-sink mounting. Its innovative design makes this device ideal for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

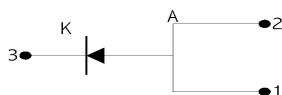
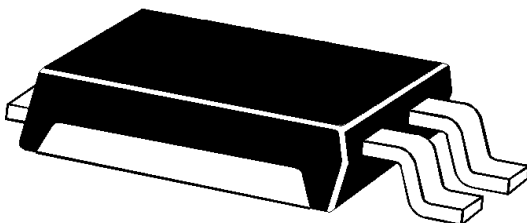
**ABSOLUTE MAXIMUM RATINGS AT 25° C
(UNLESS OTHERWISE SPECIFIED)**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	70	V
Average Rectified Output Current	I_o	5	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on Rated Load@ $T_c = 90^\circ C$	I_{FSM}	100	A
Storage Temperature	T_{STG}	-55 to +150	°C
Junction Temperature	T_J	-55 to +125	°C

THERMAL CHARACTERISTICS
Thermal Resistance


Junction-to-Case (bottom)	$R_{\theta JC}$	2.5	°C/ Watt
Junction to Ambient (1)	$R_{\theta JA}$	65	°C/ Watt

(1) When mounted on FR-4 PC board using 2 oz copper with recommended minimum foot print

Powermite 3™

KEY FEATURES

- Very low thermal resistance package
- RoHS Compliant with e3 suffix part number
- Guard-ring-die construction for transient protection
- Efficient heat path with Integral locking bottom metal tab
- Low forward voltage
- Full metallic bottom eliminates flux entrapment
- Compatible with automatic insertion
- Low profile-maximum height of 1mm

APPLICATIONS/BENEFITS

- Switching and Regulating Power Supplies.
- Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery
- Elimination of reverse-recovery oscillations to reduce need for EMI filtering
- Charge Pump Circuits
- Reduces reverse recovery loss with low I_{RM}
- Small foot print  = 190 X 260 mils (1:1 Actual size)
See mounting pad details on pg 3

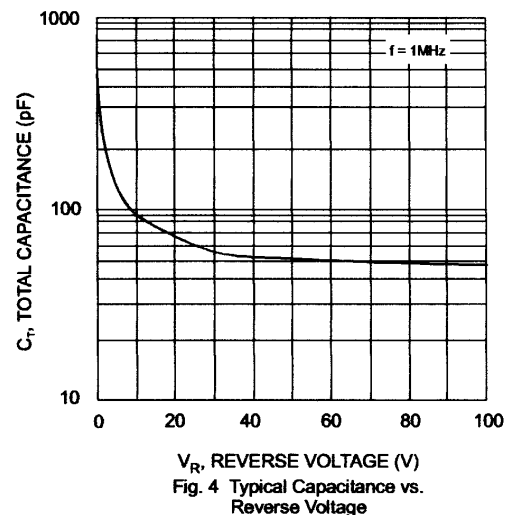
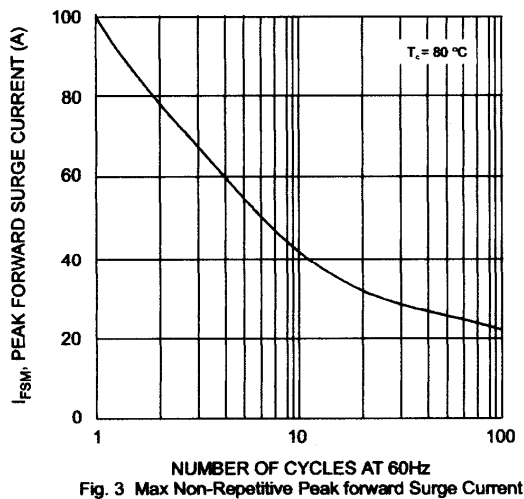
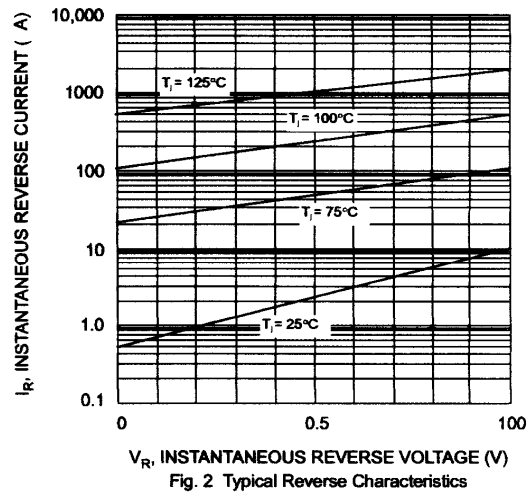
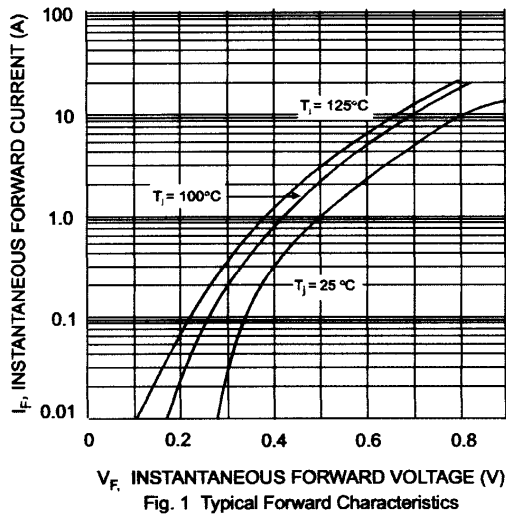
MECHANICAL & PACKAGING

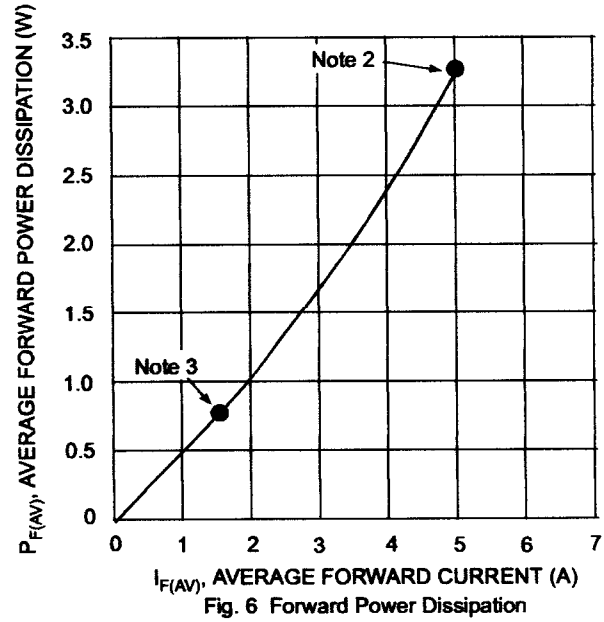
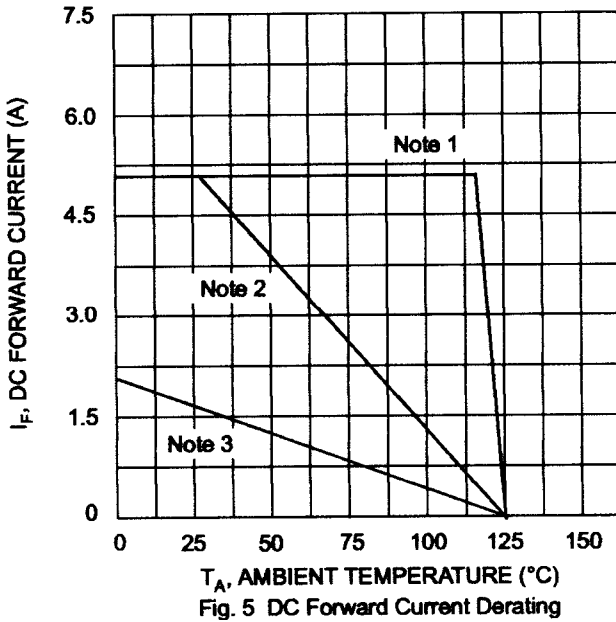
- CASE: Void-free transfer molded thermosetting epoxy compound meeting UL94V-0
- FINISH: Annealed matte-Tin plating over copper and readily solderable per MIL-STD-750 method 2026 (consult factory for Tin-Lead plating)
- POLARITY: See figure (left)
- MARKING: S5100•
- WEIGHT: 0.072 gram (approx.)
- Package dimension on last page
- Tape & Reel option: 16 mm tape per Standard EIA-481-B, 5000 on 13" reel

ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)

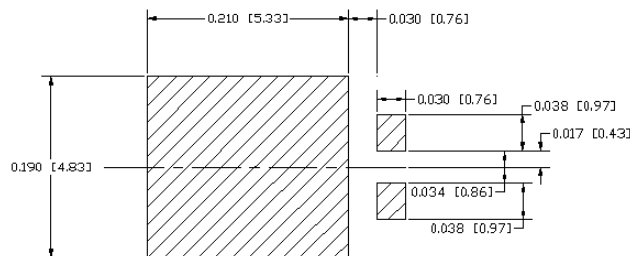
Parameter	Symbol	Conditions	Min	Typ.	Max	Units
Forward Voltage (Note 1)	V_F	$I_F = 5\text{ A}, T_L = 25\text{ °C}$ $I_F = 5\text{ A}, T_L = 125\text{ °C}$ $I_F = 10\text{ A}, T_L = 25\text{ °C}$ $I_F = 10\text{ A}, T_L = 125\text{ °C}$		0.75 0.58 0.84 0.67	0.81 0.64 0.90 0.73	V
Reverse Break Down Voltage (Note 1)	V_{BR}	$I_R = 0.2\text{ mA}$	100			V
Reverse Current (Note1)	I_R	$V_R = 100\text{V}, T_J = 25\text{ °C}$ $V_R = 100\text{V}, T_J = 125\text{ °C}$		15 10	200 20	μA mA
Capacitance	C_T	$V_R = 4\text{ V}; f = 1\text{ MHz}$		150		pF

Note: 1 Short duration test pulse used to minimize self – heating effect.

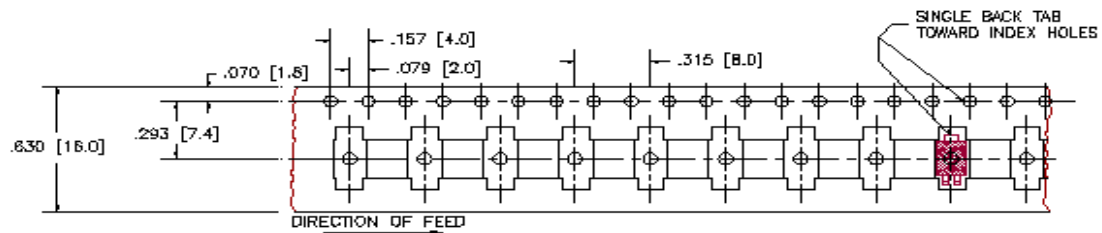
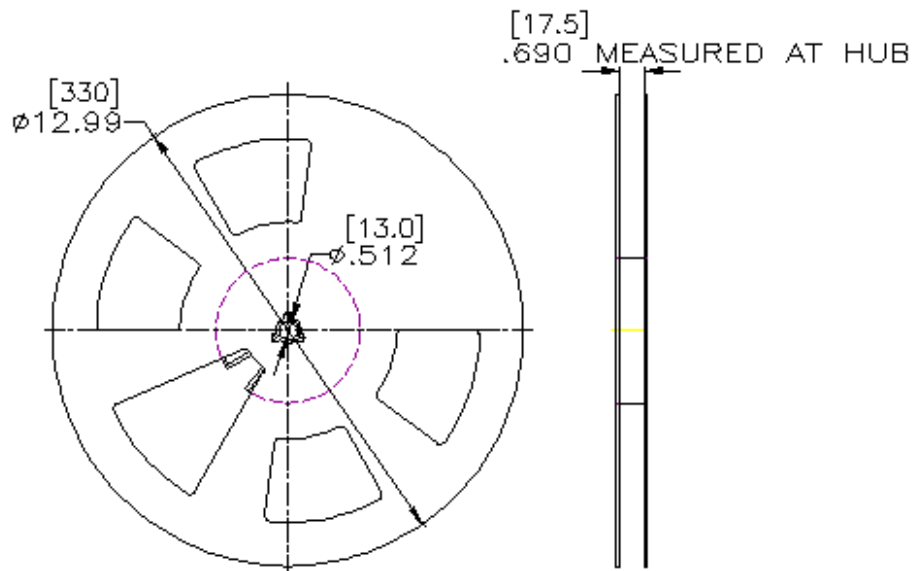


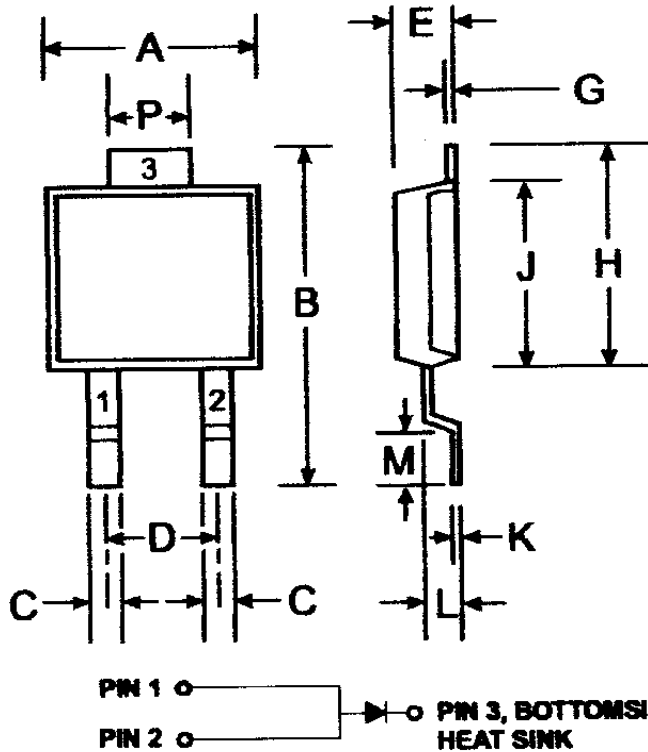


- Notes:
1. $T_A = T_{\text{SOLDERING POINT}}$, $R_{\theta JS} = 2.5^\circ\text{C/W}$, $R_{\theta SA} = 0^\circ\text{C/W}$.
 2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". $R_{\theta JA}$ in range of 20-35°C/W.
 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout $R_{\theta JA}$ in range of 65°C/W. See mounting pad below.

MOUNTING PAD LAYOUT


Mounting Pad Dimensions: inches [mm]

TAPE & REEL**13 INCH REEL**

PACKAGE DIMENSIONS


Note: Pins 1 & 2 must be electrically connected at the printed circuit board.

POWERMITE®3		
Dim	Min	Max
A	4.03	4.09
B	6.40	6.61
C	.889 NOM	
D	1.83 NOM	
E	1.10	1.14
G	.178 NOM	
H	5.01	5.17
J	4.37	4.43
K	.178 NOM	
L	.71	.77
M	.36	.46
P	1.73	1.83
All Dimensions in mm		

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Schottky Diodes & Rectifiers](#) category:

Click to view products by [Microsemi](#) manufacturer:

Other Similar products are found below :

[MA4E2039](#) [D1FH3-5063](#) [MBR0530L-TP](#) [MBR10100CT-BP](#) [MBR1545CT](#) [MMBD301M3T5G](#) [RB160M-50TR](#) [RB551V-30](#)
[BAS16E6433HTMA1](#) [BAT 54-02LRH E6327](#) [NSR05F40QNXT5G](#) [NTE555](#) [JANS1N6640](#) [SB07-03C-TB-H](#) [SB1003M3-TL-W](#) [SK310-T](#)
[SK32A-LTP](#) [SK34B-TP](#) [SS3003CH-TL-E](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM](#) [MA4E2501L-1290](#) [MBRB30H30CT-1G](#) [SB007-03C-TB-](#)
[E](#) [SK32A-TP](#) [SK33B-TP](#) [SK38B-TP](#) [NRVBM120LT1G](#) [NTE505](#) [NTSB30U100CT-1G](#) [SS15E-TP](#) [VS-6CWQ10FNHM3](#) [ACDBA1100LR-](#)
[HF](#) [ACDBA1200-HF](#) [ACDBA140-HF](#) [ACDBA2100-HF](#) [ACDBA3100-HF](#) [CDBQC0530L-HF](#) [CDBQC0240LR-HF](#) [ACDBA340-HF](#)
[ACDBA260LR-HF](#) [ACDBA1100-HF](#) [SK310B-TP](#) [MA4E2502L-1246](#) [MA4E2502H-1246](#) [NRVBM120ET1G](#) [NSR01L30MXT5G](#) [NTE573](#)
[NTE6081](#) [SB560](#)